

Twirling and spontaneous symmetry breaking of domain wall networks in lattice-reconstructed heterostructures of 2D materials

M. A. Kaliteevsky,^{1,2,*} V. V. Enaldiev,^{1,2} and V. I. Fal'ko^{1,2,3,†}

¹*National Graphene Institute, University of Manchester,
Booth St. E. Manchester M13 9PL, United Kingdom*

²*University of Manchester, School of Physics and Astronomy,
Oxford Road, Manchester M13 9PL, United Kingdom*

³*Henry Royce Institute for Advanced Materials, University of Manchester, Oxford Road, Manchester, M13 9PL, UK*

Lattice relaxation in twistrionic bilayers with close lattice parameters and almost perfect crystallographic alignment of the layers results in the transformation of moiré pattern into a sequence of preferential stacking domains and domain wall networks. Here, we show that reconstructed moiré superlattices of the perfectly aligned heterobilayers of same-chalcogen transition metal dichalcogenides have broken-symmetry structures featuring twisted nodes ('twirls') of domain wall networks. Analysing twist-angle-dependences of strain characteristics for the broken-symmetry structures we show that the formation of twirl reduces amount of hydrostatic strain around the nodes, potentially, reducing their influence on the band edge energies of electrons and holes.

This study addresses a detailed analysis of domain wall networks (DWN) which form in long-period moiré patterns characteristic for highly aligned heterostructures of same-chalcogen transition metal dichalcogenides MoX_2/WX_2 (TMDs with $\text{X}=\text{S}$ or Se). As same chalcogen TMDs have very close lattice constants, moiré patterns at their interface have long periods offering a sufficient space for creating preferential stacking areas (domains). That is, the energy gain due to better adhesion can surmount the cost of intralayer strain in each of the constituent crystals. The reconstruction of small-angle twisted bilayers into an array of domains [1] has been observed [2–6] both in MoS_2/WS_2 and $\text{MoSe}_2/\text{WSe}_2$ heterostructures. The observed [2–6] and theoretically modelled [1, 7, 8] structures feature hexagonal for anti-parallel (AP) orientation of unit cell and triangular for parallel (P) orientation of unit cells DWN.

Here, we show that lattice relaxation in P/AP- MoX_2/WX_2 ($\text{X}=\text{S}, \text{Se}$) bilayers in the limit of $\theta = 0^\circ$ twist angles undergoes symmetry breaking of the domain wall patterns resulting in formation of twirled structures of DWN nodes (see Fig. 1 for P- MoX_2/WX_2 bilayers). The emergence of twirled DWN nodes is specific for heterobilayers, in contrast to previously studied marginally twisted homobilayers (MX_2/MX_2) [1, 7, 8], where only symmetric star-like nodes have been found. This difference stems from the hydrostatic strain component determined by a small lattice mismatch of the two constituent 2D crystals. By adjusting lattice constants of MoX_2 and WX_2 inside the domains, each monolayer compression/expansion is inflicted onto domain walls creating hot spots of hydrostatic strain in the DWN nodes with XX (chalcogen over chalcogen) stacking [9]. An excessive energy costs of a large hydrostatic strain around XX nodes (as compared to shear deformations dominating DWN structure in homobilayers) is, then, negotiated by left/right-handed twirling of the domain walls, leading to a broken-symmetry configuration sketched in Fig.

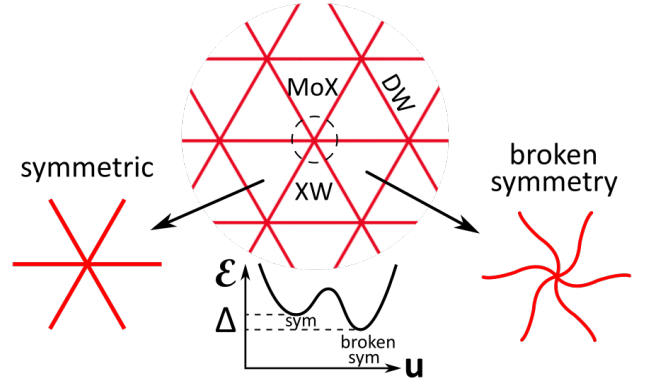


Figure 1. Symmetric and broken-symmetry (twirl) structures of DWN in aligned P- MoX_2/WX_2 bilayers. Bottom plot shows energy gain (Δ) from the formation of twirls.

1. Methods.

To study lattice relaxation in MoX_2/WX_2 bilayers we use multiscale modelling approach developed in Refs. [1, 10]. This combines mesoscale elasticity with analytically interpolated description of adhesion energy of two layers, computed using density functional theory (DFT). The latter is represented below upon taken into account interlayer distance relaxation (see SM):

$$W_{\text{P/AP}}(\mathbf{r}_0) = \sum_{n,l=1,2,3} \left[w_n^{(s)} \cos(\mathbf{G}_l^{(n)} \mathbf{r}_0) + w_n^{(a)} \sin(\mathbf{G}_l^{(n)} \mathbf{r}_0 + \gamma_{\text{P/AP}}) \right]. \quad (1)$$

Here, \mathbf{r}_0 is a locally defined in-plane vector determining stacking arrangement between layers ($\mathbf{r}_0 = \mathbf{0}$ for XX stacking, $\mathbf{r}_0 = (0, -a/\sqrt{3})$ for XW/2H stacking and $\mathbf{r}_0 = (0, a/\sqrt{3})$ for MoX/MoW stacking in P/AP-heterostructures), phases $\gamma_{\text{P}} = \pi/2$, $\gamma_{\text{AP}} = 0$ account $\mathbf{r}_0 \rightarrow -\mathbf{r}_0$ symmetry of the adhesion energy in P- and

AP-bilayers [1]; $G_{1,2,3}^{(1,2,3)}$ are three sets of the shortest reciprocal lattice vectors ($|G_{1,2,3}^{(1)}| = G$, $|G_{1,2,3}^{(2)}| = G\sqrt{3}$, $|G_{1,2,3}^{(3)}| = 2G$) of a commensurate MoX_2/WX_2 heterostructure, related by 120° -rotations within each set. The values of parameters $w_{1,2,3}^{(s,a)}$ established using DFT [1, 10] are listed in Table I.

Next, we combine (1) with elasticity theory by substituting

tuting local stacking in the form,

$$\mathbf{r}_0(\mathbf{r}) = \delta \cdot \mathbf{r} + \theta \hat{z} \times \mathbf{r} + \mathbf{u}^{\text{Mo}} - \mathbf{u}^{\text{W}}, \quad (2)$$

where $\delta \approx 0.2\%$ for MoS_2/WS_2 bilayers and $\delta \approx 0.4\%$ for $\text{MoSe}_2/\text{WSe}_2$; $\mathbf{u}^{\text{Mo}}(\mathbf{r})$ and $\mathbf{u}^{\text{W}}(\mathbf{r})$ are in-plane displacement fields describing lattice relaxation in MoX_2 and WX_2 layers, respectively. Then, we minimise total energy of moiré superlattice,

$$\mathcal{E} = \int d^2\mathbf{r} \left\{ W_{\text{AP/P}}(\mathbf{r}_0(\mathbf{r})) + \sum_{l=\text{W,Mo}} \left[\frac{\lambda_l + \mu_l}{2} (\text{div} \mathbf{u}^{(l)})^2 + \frac{\mu_l}{2} \left((u_{xx}^{(l)} - u_{yy}^{(l)})^2 + 4u_{xy}^{(l)2} \right) \right] \right\}, \quad (3)$$

with respect to the displacement fields \mathbf{u}^{W} and \mathbf{u}^{Mo} . Here, $\lambda_{\text{Mo,W}}$, $\mu_{\text{Mo,W}}$ are elastic moduli of MoX_2 and WX_2 monolayers (see Table I), and $u_{ij}^l = (\partial_j u_i^l + \partial_i u_j^l)/2$ are components of strain tensors.

Table I. Adhesion [1] and elastic [11, 12] energy parameters (in eV/nm²) used in Eq. (3).

X	$w_1^{(s)}$	$w_1^{(a)}$	$w_2^{(s)}$	$w_2^{(a)}$	$w_3^{(s)}$	$w_3^{(a)}$
S, AP	0.1415	0.0269	-0.0338	0	-0.0166	-0.0030
S, P	0.1559	0	-0.0398	0	-0.0199	0
Se, AP	0.1128	0.0256	-0.0201	0	-0.0098	-0.0024
Se, P	0.1284	0	-0.0248	0	-0.0124	0
X	λ_{W}	λ_{Mo}	μ_{W}	μ_{Mo}		
S	328.2	520.1	453.2	443.0		
Se	185.5	264.3	302.6	310.3		

To find optimal distributions of displacement fields, \mathbf{u}^{W} and \mathbf{u}^{Mo} , we solve a system of Lagrange-Euler equations, with periodic boundary conditions, implemented via the finite difference method. In particular, we chose rectangular supercell with $\ell\sqrt{3}/2$ and ℓ sides ($\ell = a/\sqrt{\delta^2 + \theta^2}$ is the moiré superlattice period, a is averaged monolayer lattice parameter), setting the following boundary conditions: $\mathbf{u}^{\text{Mo/W}}(0, y') = \mathbf{u}^{\text{Mo/W}}(\ell\sqrt{3}/2, y' \mp \ell/2)$, at $0 \leq \pm y' \leq \ell/2$, and $\mathbf{u}^{\text{Mo/W}}(x', \ell/2) = \mathbf{u}^{\text{Mo/W}}(x', -\ell/2)$. Here, prime superscripts indicate that $x'Oy'$ reference frame was rotated by an angle $\phi = \pi/6 + \arctan[(\sqrt{3}\delta - \theta)/(\sqrt{3}\theta + \delta)]$ with respect to the fixed frame for which Ox and Oy axes are along zigzag and armchair directions in the crystal, respectively. Such a rotation allows us to fix boundary conditions (note that the Lagrange-Euler equations themselves are rotational-invariant).

In the numerical analysis we use a sufficiently dense grid (one point per nm) to provide convergence of the computed displacement fields. This requires solving ~ 30000 coupled nonlinear equations. This solution is ob-

tained in an annealing-type computational scheme: first, we choose the starting point as $\mathbf{u}^{\text{Mo/W}} = \mathbf{0}$ and scale down the adhesion energy parameters $w_{1,2,3}^{(s,a)}$ by a small factor $\eta = 10^{-3}$, finding slightly relaxed structure. Then, we gradually enlarge this factor, up to $\eta = 1$ (at the final step), using solutions obtained at the previous iterations as starting points at each next step.

Twirls in P-MoX₂/WX₂ heterostructures. Lattice relaxation in P-MoX₂/WX₂ heterostructures results in formation of DWN separating triangular domains with MoX and XW stackings, similar to those found in 3R-TMD polytypes [2, 3] (see Fig. 2). Minimising functional (3) we find the following three competing distributions of strain. One of them (symmetric), shown on the middle panels, is characterized by straight edge dislocation lines linking XX stacking nodes of DWN. The other two (left and right panels) are twirled (broken-symmetry) structures of DWN nodes with a left/right-handed twist. The computed total energies per supercell, gathered in Table II, show that the twirled DWN structure has lower energy than the symmetric one. Note that left/right-handed twirls have the same energy suggesting that DWN in perfectly aligned heterostructure ($\theta = 0^\circ$) undergoes a spontaneous symmetry breaking into twirled state.

Values of adhesive and elastic energies compared in Table II also suggest that the dominant energy gain for the twirled structures comes from lowering elastic energy. The latter is determined by hydrostatic strain, $\text{div} \mathbf{u}$, and shear deformations, characterized by a vector, $\mathbf{A} = (u_{xx} - u_{yy}, -2u_{xy})$. Their distribution across DWN is shown Fig. 2, in the form of color maps for $\text{div} \mathbf{u}$ and $|\mathbf{A}|$. Here, the difference between symmetric and twirled structures is such that hydrostatic strain component, concentrated around nodes, is higher for symmetric one. Since energy costs of the hydrostatic strain ($\propto \lambda + \mu$) are higher than those of shear strain ($\propto \mu$), the twirled structures emerge as energetically favourable.

In Fig. 3 we analyse dependence of $\text{div} \mathbf{u}$ and \mathbf{A} on the twist angle. The data shown in Fig. 3(i) indicate

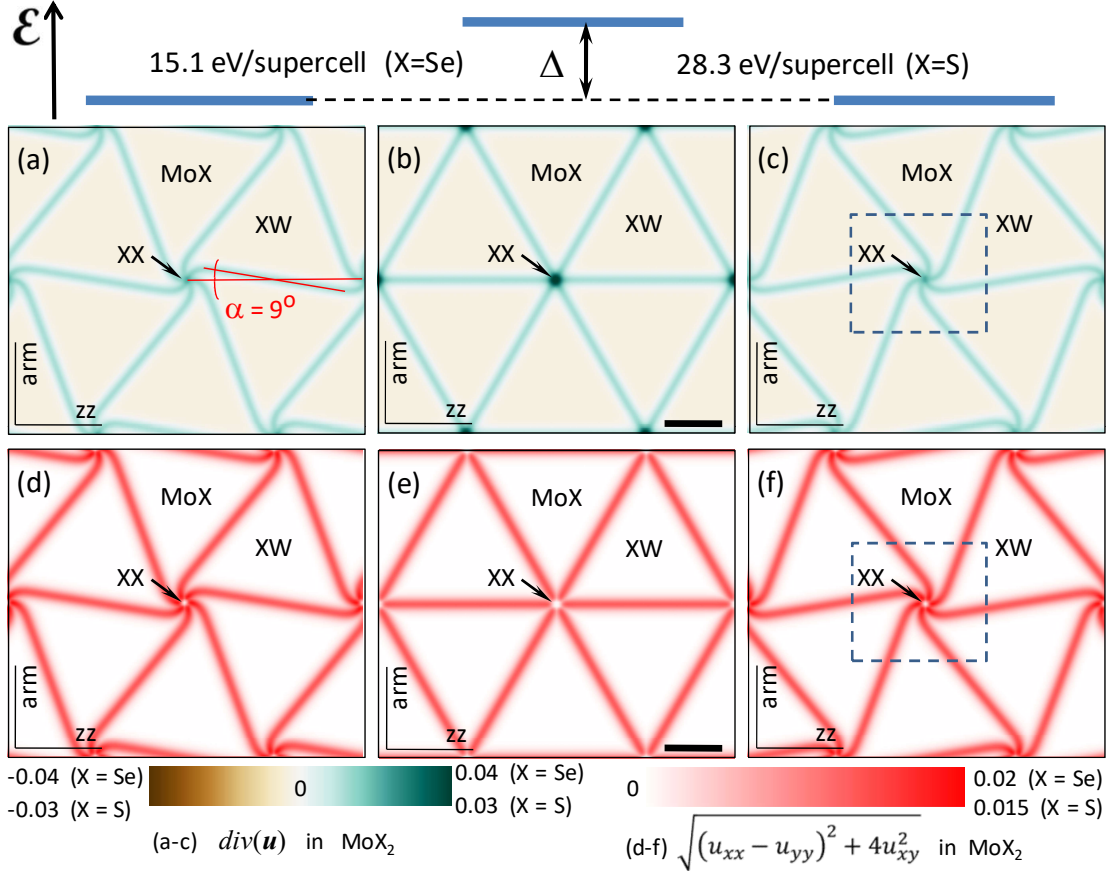


Figure 2. Maps of hydrostatic (a-c) and shear (d-f) components of strain tensor in principal axes for symmetric (b) and twirled (a,c) structures of reconstructed moiré superlattice in aligned P-MoX₂/WX₂ bilayers. Sketch on the top shows energy gain from formation of twirled structures. Scale bar is 30 nm and 45 nm for X=Se and X=S, respectively. Dashed rectangles on (c) and (f) show area displayed in Fig. 3.

Table II. Values of adhesion, elastic, total energies (in eV/supercell) computed for symmetric (sym) and twirled (twirl) moiré superlattice structures and their total energy differences, Δ , in aligned P-MoX₂/WX₂ bilayers.

X	structure	elastic	adhesion	total	Δ
Se	sym	223.01	-2349.68	-2126.67	15.12
	twirl	208.95	-2350.74	-2141.79	
S	sym	349.92	-5321.11	-4971.19	28.26
	twirl	323.33	-5322.78	-4999.45	

that the maximal value of $\text{div} \mathbf{u}$ at the hot spot of strain decreases with the twist, which also explains why twirling is weaker for larger θ 's. Another deformation field characteristic which is interesting to consider is $B^* = [\text{rot} \mathbf{A}]_z = 2\partial_x u_{xy}^{\text{Mo(W)}} + \partial_y (u_{xx}^{\text{Mo(W)}} - u_{yy}^{\text{Mo(W)}})$. This characteristic determines the size of piezoelectric

charges, generated by inhomogeneous strain in each layer, and pseudomagnetic field that would be experienced by charge carriers at the K-valley band edge in the heterostructure [1, 10]. Note that in P-heterostructures piezocharges ($\propto e_{11} B^*$) have opposite signs in MoX₂ and WX₂ layers, as $B_{\text{Mo}}^* \approx -B_{\text{W}}^*$, and piezocoefficients have the same signs, $e_{11}^{\text{Mo}} \approx e_{11}^{\text{W}}$. For the displayed range of angles, $0^\circ \leq \theta \lesssim 0.4^\circ$, distributions of B^* shows change of sign and zero value in the middle of the domain wall. For larger twist angles $\theta \gg \delta$ piezocharge and pseudomagnetic field distributions take the form of those established earlier for homobilayers [1].

Twirls in AP-MoX₂/WX₂ heterostructures. Lattice relaxation in AP-MoX₂/WX₂ heterostructures leads to the formation of hexagonal domains of 2H-like stacking (simultaneous metal-on-chalcogen and chalcogen-on-metal like in bulk 2H TMD crystals). Those domains are separated by a hexagonal DWN with two inequivalent nodes:

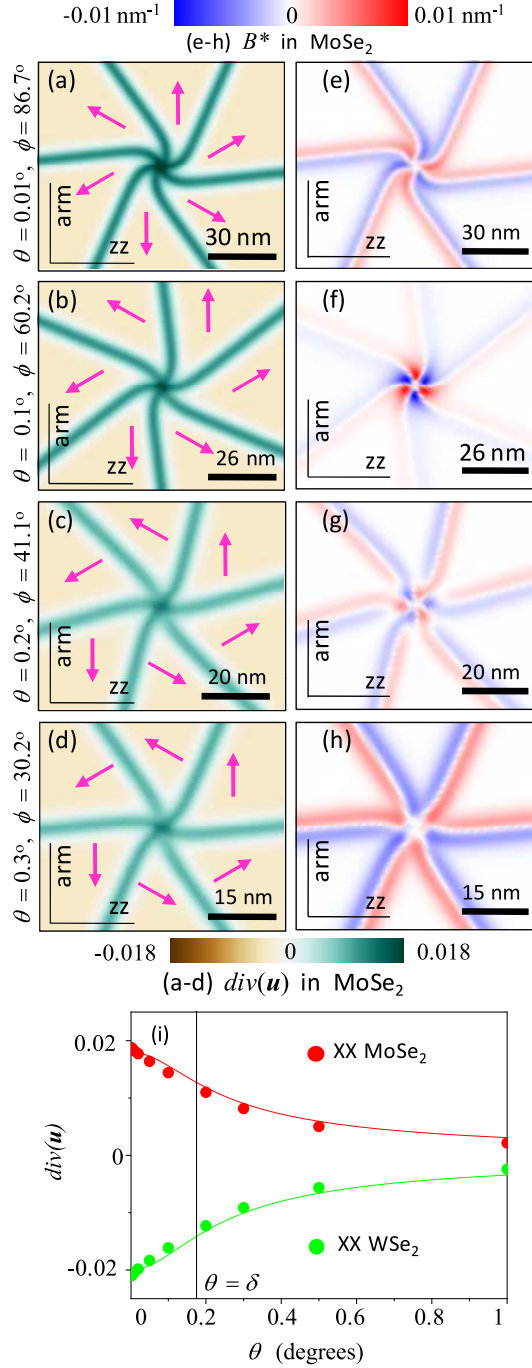


Figure 3. Twirl in P-MoSe₂/WSe₂ for $\theta = 0.01^\circ, 0.1^\circ, 0.2^\circ$ and 0.3° . (a-d) show maps of $\text{div} \mathbf{u}_{\text{Mo}}$. The arrows indicate direction of stacking vector \mathbf{r}_0 ($|\mathbf{r}_0| = a/\sqrt{3}$) inside domains; (e-h) show $B^* = 2\partial_x u_{xy}^{\text{Mo}} + \partial_y(u_{xx}^{\text{Mo}} - u_{yy}^{\text{Mo}})$. (i) Values of $\text{div} \mathbf{u}_{\text{Mo,W}}$ at twirl center for various twist angles.

one with XX stacking (chalcogen-on-chalcogen) and the other with two metallic site on the top of each other, MoW. Upon minimising energy in Eq. (3) for crystallographically aligned bilayers, we identify two candidates for the lowest energy configuration of DWN: symmetric and left/right-handed twirled structures, Fig.

Table III. Values of adhesion, elastic, total energies (in eV/supercell) computed for symmetric (sym) and twirled (twirl) structures and total energy differences, Δ , for aligned AP-MoX₂/WX₂ bilayers.

X	structure	elastic	adhesion	total	Δ
Se	sym	329.46	-2648.55	-2319.09	6.12
	twirl	323.77	-2648.98	-2325.21	
S	sym	496.25	-5904.35	-5408.10	14.44
	twirl	482.70	-5905.24	-5422.54	

4. Twirled structures form around XX nodes, whereas DWN around MoW nodes is almost unchanged (only rotated as a whole by $\approx 5^\circ$), which is because those nodes host metastable MoW stacking with much weaker hydrostatic strain component as compared to XX nodes). Energies of symmetric and twirled structures compared in Table III show that the broken-symmetry structure is energetically favourable.

In Fig. 5 we show twist angle dependences of strain field characteristics around a single twirl. The data for $\text{div} \mathbf{u}$ in Fig. 5(i) indicate decrease of its magnitude (in each of the layers) with the twist angle. This trend corresponds to the decay of twirling with growth of layers' misorientation (Fig. 5(a-d)) as already discussed about P-heterostructures in the previous section. We also point out that, in contrast to P-bilayers, for AP-heterostructures shear strain results in the same signs of piezocharge densities ($\propto e_{11}^{\text{Mo}} B_{\text{Mo}}^* \approx e_{11}^{\text{W}} B_{\text{W}}^*$) in both layers (opposite signs of piezocoefficients, $e_{11}^{\text{Mo}} \approx -e_{11}^{\text{W}}$, due to anti-alignment of layers, are compensated by signs inversion for $B_{\text{Mo}}^* \approx -B_{\text{W}}^*$). Note that DWN nodes host area of non-zero B^* , which reverses sign at $\theta \approx \delta$, with magnitude at MoW nodes substantially higher than that of twirled nodes (see Fig. 5(j)).

Conclusion. The main finding of this study consists in the prediction of a spontaneous symmetry breaking in the form of domain wall network in MoX₂/WX₂ heterostructures. For almost perfectly aligned MoX₂/WX₂ bilayers, this symmetry breaking consists in the formation of twirl-shaped nodes, accompanied by substantial reduction of a hydrostatic strain component in the vicinity of those nodes - as compared to earlier-studied symmetric (non-twirled) DWN structures [9]. The reduction of hydrostatic strain component by twirling could have a pronounced effect in the energetics of the band edge states of the electrons and holes, making those less confined at the twirled nodes, as compared to symmetric nodes. As a result, the earlier studies [9] overestimated electron, hole and exciton bindings by the XX DWN nodes, so that the analysis of electron, hole and interlayer excitons localisation at the twirls requires farther studies.

Acknowledgement. We acknowledge useful discussions with Marek Potemski, Isaac Ochoa and Fabio Ferreira. This work was supported by EC-FET Core 3 European

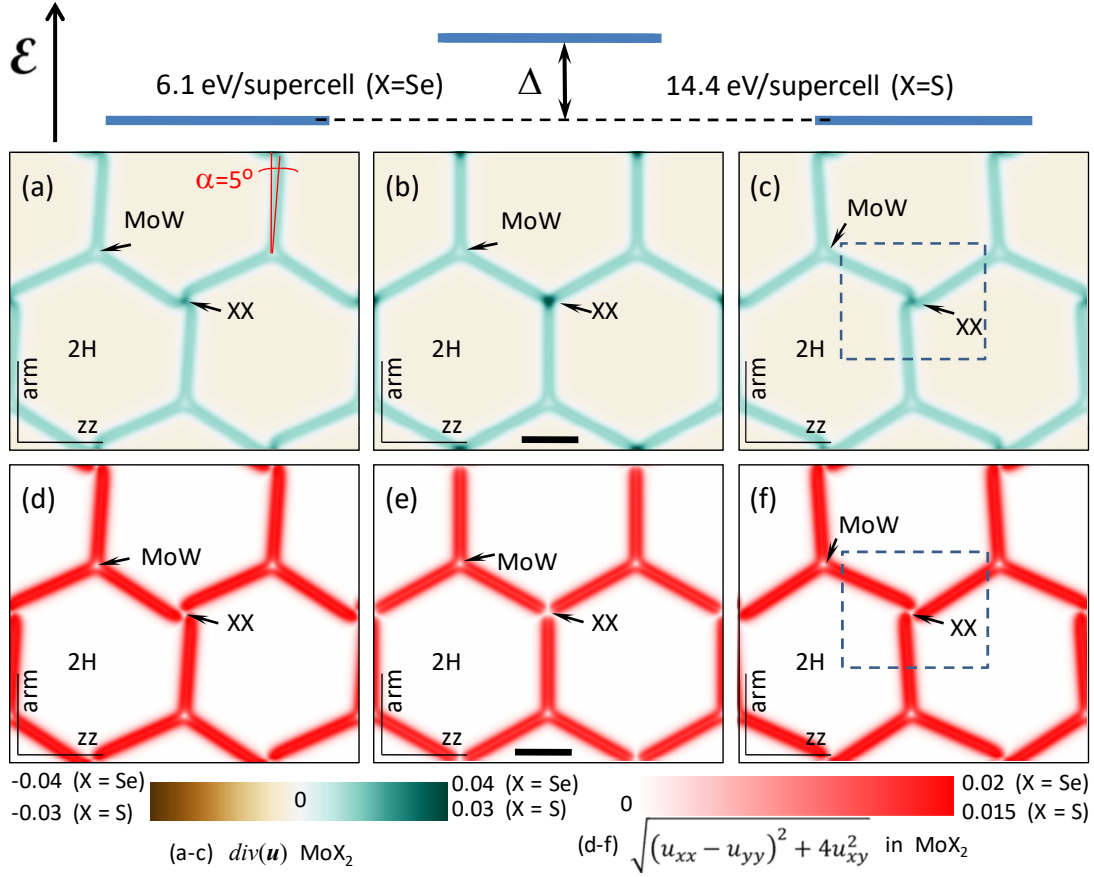


Figure 4. Maps of hydrostatic (a-c) and shear (d-f) components of strain tensor in principal axes for symmetric (b) and twirled (a,c) structures of reconstructed moiré superlattice in aligned AP-MoX₂/WX₂ bilayers. Sketch on the top shows energy gain from formation of twirled structures. Scale bar is 30 nm and 45 nm for X=Se and X=S, respectively. Dashed rectangles on (c) and (f) show area displayed in Fig. 5.

Graphene Flagship Project, EC-FET Quantum Flagship Project 2D-SIPC, EPSRC grants EP/S030719/1 and EP/V007033/1, and the Lloyd Register Foundation Nanotechnology Grant.

Author Contributions. MAK, VVE, and VIF contributed equally to this paper. MAK and VVE developed formalism and software and carried out calculations. VIF conceived the paper. All authors contributed to the data analysis and manuscript writing.

* mikhail.kaliteevski@manchester.ac.uk

† vladimir.falko@manchester.ac.uk

[1] V. V. Enaldiev, V. Zólyomi, C. Yelgel, S. J. Magorrian, and V. I. Fal'ko, Stacking domains and dislocation networks in marginally twisted bilayers of transition metal dichalcogenides, *Phys. Rev. Lett.* **124**, 206101 (2020).

[2] A. Weston, Y. Zou, V. Enaldiev, A. Summerfield, N. Clark, V. Zólyomi, A. Graham, C. Yelgel, S. Magorrian, M. Zhou, J. Zultak, D. Hopkinson, A. Barinov, T. H. Bointon, A. Kretinin, N. R. Wilson, P. H. Beton, V. I. Fal'ko, S. J. Haigh, and R. Gorbachev, Atomic reconstruction in twisted bilayers of transition metal dichalcogenides, *Nature Nanotechnology* **15**, 592 (2020).

[3] M. R. Rosenberger, H.-J. Chuang, M. Phillips, V. P. Oleshko, K. M. McCreary, S. V. Sivaram, C. S. Hellberg, and B. T. Jonker, Twist angle-dependent atomic reconstruction and moiré patterns in transition metal dichalcogenide heterostructures, *ACS Nano* **14**, 4550 (2020).

[4] J. Sung, Y. Zhou, G. Scuri, V. Zólyomi, T. I. Andersen, H. Yoo, D. S. Wild, A. Y. Joe, R. J. Gelly, H. Heo, S. J. Magorrian, D. Bérubé, A. M. M. Valdivia, T. Taniguchi, K. Watanabe, M. D. Lukin, P. Kim, V. I. Fal'ko, and H. Park, Broken mirror symmetry in excitonic response of reconstructed domains in twisted MoSe₂/MoSe₂ bilayers, *Nature Nanotechnology* **15**, 750 (2020).

[5] L. J. McGilly, A. Kerelsky, N. R. Finney, K. Shapovalov,

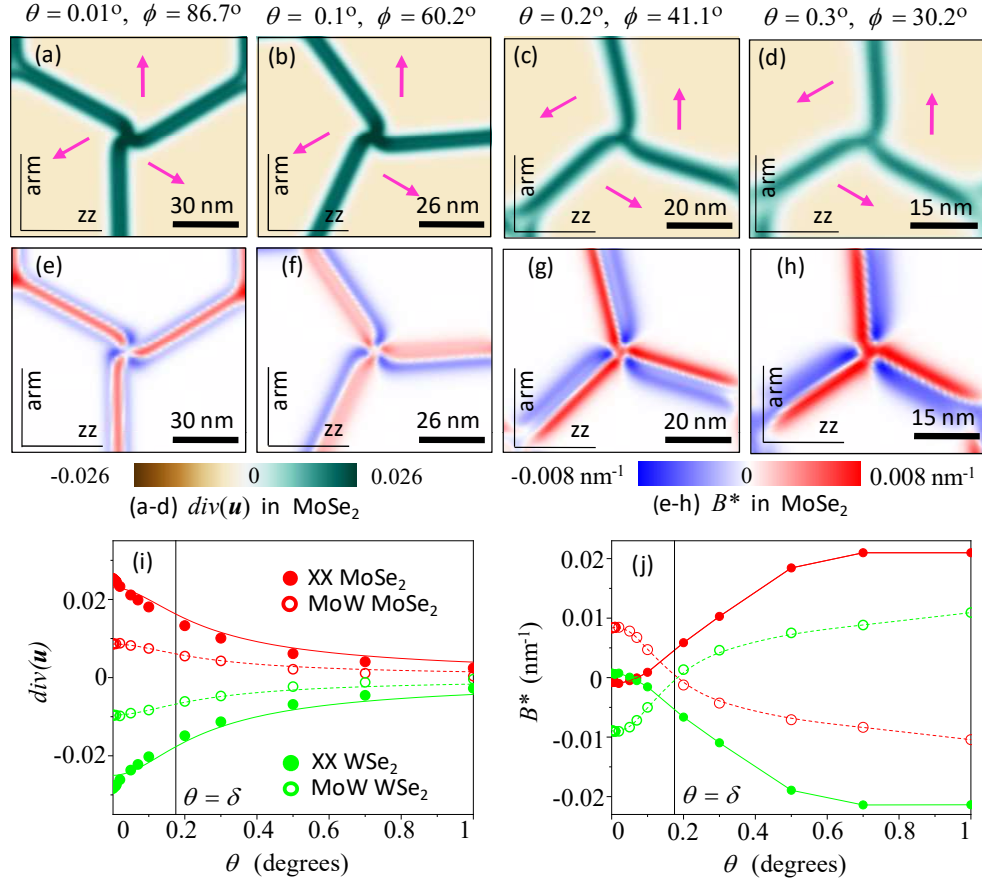


Figure 5. Twirl in AP-MoSe₂/WSe₂ for $\theta = 0.01^\circ, 0.1^\circ, 0.2^\circ$ and 0.3° . (a-d) show maps of $\text{div}\mathbf{u}_{\text{Mo}}$. The arrows indicate direction of stacking vector \mathbf{r}_0 ($|\mathbf{r}_0| = a/\sqrt{3}$) inside domains; (e-h) show $B^* = 2\partial_x u_{xy}^{\text{Mo}} + \partial_y(u_{xx}^{\text{Mo}} - u_{yy}^{\text{Mo}})$. (i) Values of $\text{div}\mathbf{u}_{\text{Mo,W}}$ at twirl center for various twist angles. (j) B^* -dependence in centers of XX (twirl) and MoW nodes.

- E.-M. Shih, A. Ghiotto, Y. Zeng, S. L. Moore, W. Wu, Y. Bai, K. Watanabe, T. Taniguchi, M. Stengel, L. Zhou, J. Hone, X. Zhu, D. N. Basov, C. Dean, C. E. Dreyer, and A. N. Pasupathy, Visualization of moiré superlattices, *Nature Nanotechnology* **15**, 580 (2020).
- [6] S. Shabani, D. Halbertal, W. Wu, M. Chen, S. Liu, J. Hone, W. Yao, D. N. Basov, X. Zhu, and A. N. Pasupathy, Deep moiré potentials in twisted transition metal dichalcogenide bilayers, *Nature Physics* **17**, 720 (2021).
- [7] M. H. Naik and M. Jain, Ultraflatbands and shear solitons in moiré patterns of twisted bilayer transition metal dichalcogenides, *Phys. Rev. Lett.* **121**, 266401 (2018).
- [8] S. Carr, D. Massatt, S. B. Torrisi, P. Cazeaux, M. Lusk, and E. Kaxiras, Relaxation and domain formation in incommensurate two-dimensional heterostructures, *Phys. Rev. B* **98**, 224102 (2018).
- [9] V. V. Enaldiev, F. Ferreira, J. G. McHugh, and V. I. Fal'ko, Self-organized quantum dots in marginally twisted MoSe₂/WSe₂ and MoS₂/WS₂ bilayers, *npj 2D Materials and Applications* **6**, 74 (2022).
- [10] V. V. Enaldiev, F. Ferreira, S. J. Magorrian, and V. I. Fal'ko, Piezoelectric networks and ferroelectric domains in twistronic superlattices in WS₂/MoS₂ and WSe₂/MoSe₂ bilayers, *2D Materials* **8**, 025030 (2021).
- [11] N. Iguñiz, R. Frisenda, R. Bratschitsch, and A. Castellanos-Gomez, Revisiting the buckling metrology method to determine the young's modulus of 2d materials, *Advanced Materials* **31**, 1807150 (2019).
- [12] C. Androulidakis, K. Zhang, M. Robertson, and S. Tawfick, Tailoring the mechanical properties of 2d materials and heterostructures, *2D Materials* **5**, 032005 (2018).